ON Semiconductor

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TinyLogic ULP-A OR Gate

NC7SP32

The NC7SP32 is a single 2–input OR gate in tiny footprint packages. The device is designed to operate for $V_{CC} = 0.9 \text{ V}$ to 3.6 V.

Features

- Designed for 0.9 V to 3.6 V V_{CC} Operation
- 2.7 ns t_{PD} at 3.3 V (Typ)
- Inputs/Outputs Over-Voltage Tolerant up to 3.6 V
- I_{OFF} Supports Partial Power Down Protection
- Source/Sink 2.6 mA at 3.3 V
- Available in SC−88A and MicroPak[™] Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

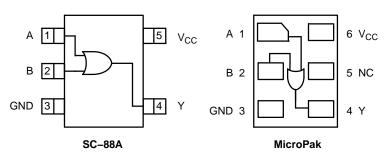


Figure 1. Pinout Diagrams (Top Views)



Figure 2. Logic Symbol

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MARKING DIAGRAMS



SIP6 1.45X1.0 MicroPak CASE 127EB



CC = Specific Device Code

= 2-Digit Lot Run Traceability Code

XY = 2-Digit Date CodeZ = Assembly Plant Code



ΚK

SC-88A CASE 419A-02



XXX = Specific Device Code

M = Date Code

■ = Pb-Free Package

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

PIN ASSIGNMENT

| Pin | SC88A | MicroPak | | |
|-----|-----------------|-----------------|--|--|
| 1 | А | А | | |
| 2 | В | В | | |
| 3 | GND | GND | | |
| 4 | Υ | Υ | | |
| 5 | V _{CC} | N.C. | | |
| 6 | - | V _{CC} | | |

N.C. = No Connect

FUNCTION TABLE

| Inp | Output | |
|-----|--------|---|
| А | В | Υ |
| L | L | L |
| L | Н | Н |
| Н | L | Н |
| Н | Н | Н |

MAXIMUM RATINGS

| Symbol | Characteristics | | Value | Unit |
|-------------------------------------|---|---|---|------|
| V _{CC} | DC Supply Voltage | | -0.5 to +4.3 | V |
| V _{IN} | DC Input Voltage | | -0.5 to +4.3 | V |
| V _{OUT} | | e-Mode (High or Low State) Tri-State Mode (Note 1) er-Down Mode (V _{CC} = 0 V) | -0.5 to V _{CC} + 0.5 -0.5 to +4.3 -0.5 to +4.3 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < GND | - 50 | mA |
| I _{OK} | DC Output Diode Current | V _{OUT} < GND | - 50 | mA |
| l _{OUT} | DC Output Source/Sink Current | | ±50 | mA |
| I _{CC} or I _{GND} | DC Supply Current per Supply Pin or Ground Pin | | ±50 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds | | 260 | °C |
| TJ | Junction Temperature Under Bias | | +150 | °C |
| θJA | Thermal Resistance (Note 2) | SC-88A MicroPak | 377 154 | °C/W |
| P _D | Power Dissipation in Still Air | SC-88A MicroPak | 332 812 | mW |
| MSL | Moisture Sensitivity | | Level 1 | - |
| F _R | Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | - |
| V _{ESD} | ESD Withstand Voltage (Note 3) | Human Body Model Charged Device Model | 2000 1000 | V |
| I _{Latchup} | Latchup Performance (Note 4) | | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Applicable to devices with outputs that may be tri-stated.
 Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
- 4. Tested to EIA/JÉSD78 Class II.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Min | Max | Unit |
|---------------------------------|-------------------------------------|---|-------------|-------------------------------|------|
| V _{CC} | Positive DC Supply Voltage | | 0.9 | 3.6 | V |
| V_{IN} | DC Input Voltage | | 0 | 3.6 | V |
| V _{OUT} | DC Output Voltage | Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode (V _{CC} = 0 V) | 0 0 0 | V _{CC} 3.6 3.6 | |
| T _A | Operating Temperature Range | | -40 | +85 | °C |
| t _r , t _f | Input Transition Rise and Fall Time | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | 0 | 10 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| | | | | Т | A = 25° | С | $T_A = -40^{\circ}$ | C to +85°C | |
|------------------|------------------------------|--|---------------------|------------------------|-----------------------|------------------------|------------------------|------------------------|------|
| Symbol | Parameter | Condition | V _{CC} (V) | Min | Тур | Max | Min | Max | Unit |
| V_{IH} | High-Level Input | | 0.9 | _ | 0.5 | _ | - | - | V |
| | Voltage | | 1.1 to 1.3 | 0.65 x V _{CC} | - | _ | 0.65 x V _{CC} | - | |
| | | | 1.4 to 1.6 | 0.65 x V _{CC} | _ | _ | 0.65 x V _{CC} | - | |
| | | | 1.65 to 1.95 | 0.65 x V _{CC} | - | - | 0.65 x V _{CC} | - | |
| | | | 2.3 to 2.7 | 1.6 | _ | - | 1.6 | - | |
| | | | 3.0 to 3.6 | 2.1 | _ | _ | 2.1 | - | |
| V _{IL} | Low-Level Input | | 0.9 | - | 0.5 | _ | - | - | V |
| | Voltage | | 1.1 to 1.3 | - | _ | 0.35 x V _{CC} | - | 0.35 x V _{CC} | |
| | | | 1.4 to 1.6 | - | _ | 0.35 x V _{CC} | - | 0.35 x V _{CC} | |
| | | | 1.65 to 1.95 | _ | _ | 0.35 x V _{CC} | - | 0.35 x V _{CC} | |
| | | | 2.3 to 2.7 | - | _ | 0.7 | - | 0.7 | |
| | | | 3.0 to 3.6 | _ | _ | 0.9 | _ | 0.9 | |
| V _{OH} | High-Level Output | $V_{IN} = V_{IH}$ or V_{IL} | | | | | | | V |
| | Voltage | I _{OH} = -20 μA | 0.9 | - | V _{CC} - 0.1 | - | - | - | |
| | | | 1.1 to 1.3 | V _{CC} - 0.1 | _ | _ | V _{CC} – 0.1 | - | |
| | | | 1.4 to 1.6 | V _{CC} - 0.1 | _ | _ | V _{CC} - 0.1 | - | |
| | | | 1.65 to 1.95 | V _{CC} - 0.1 | _ | _ | V _{CC} - 0.1 | - | |
| | | | 2.3 to 2.7 | V _{CC} – 0.1 | _ | _ | V _{CC} - 0.1 | - | |
| | | | 3.0 to 3.6 | V _{CC} - 0.1 | _ | _ | V _{CC} – 0.1 | - | |
| | | $I_{OH} = -0.5 \text{ mA}$ | 1.1 to 1.3 | 0.75 x V _{CC} | _ | _ | 0.70 x V _{CC} | - | |
| | | $I_{OH} = -1 \text{ mA}$ | 1.4 to 1.6 | 1.07 | - | - | 0.99 | - | |
| | | $I_{OH} = -1.5 \text{ mA}$ | 1.65 to 1.95 | 1.24 | - | _ | 1.22 | - | |
| | | $I_{OH} = -2.1 \text{ mA}$ | 2.3 to 2.7 | 1.95 | - | - | 1.87 | - | |
| | | $I_{OH} = -2.6 \text{ mA}$ | 3.0 to 3.6 | 2.61 | _ | _ | 2.55 | - | |
| V_{OL} | Low-Level Output | $V_{IN} = V_{IH}$ or V_{IL} | | | | | | | V |
| | Voltage | I _{OL} = 20 μA | 0.9 | _ | 0.1 | _ | - | - | |
| | | | 1.1 to 1.3 | _ | - | 0.1 | - | 0.1 | |
| | | | 1.4 to 1.6 | _ | - | 0.1 | - | 0.1 | |
| | | | 1.65 to 1.95 | - | - | 0.1 | - | 0.1 | |
| | | | 2.3 to 2.7 | _ | - | 0.1 | - | 0.1 | |
| | | | 3.0 to 3.6 | _ | _ | 0.1 | - | 0.1 | |
| | | $I_{OL} = 0.5 \text{ mA}$ | 1.1 to 1.3 | - | _ | 0.3 x V _{CC} | - | 0.3 x V _{CC} | |
| | | I _{OL} = 1 mA | 1.4 to 1.6 | - | _ | 0.31 | - | 0.37 | |
| | | I _{OL} = 1.5 mA | 1.65 to 1.95 | _ | _ | 0.31 | - | 0.35 | |
| | | I _{OL} = 2.1 mA | 2.3 to 2.7 | _ | - | 0.31 | _ | 0.33 | |
| | | I _{OL} = 2.6 mA | 3.0 to 3.6 | _ | - | 0.31 | - | 0.33 | |
| I _{IN} | Input Leakage Current | V _{IN} = 0 V to 3.6 V | 0.9 to 3.6 | - | _ | ±0.1 | - | ±0.5 | μΑ |
| I _{OFF} | Power Off Leakage Current | V _{IN} = 0 V to 3.6 V or V _{OUT} = 0 V to 3.6 V | 0 | - | _ | 0.5 | - | 0.5 | μΑ |
| I _{CC} | Quiescent Supply Current | $V_{IN} = V_{CC}$ or GND | 0.9 to 3.6 | - | _ | 0.9 | - | 0.9 | μΑ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

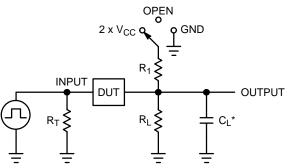
AC ELECTRICAL CHARACTERISTICS

| | | | | ٦ | Γ _A = 25°(| C | $T_A = -40^{\circ}C$ | C to +85°C | |
|-------------------------------------|------------------------------------|---|---------------------|-----|-----------------------|----------|----------------------|------------|------|
| Symbol | Parameter | Condition | V _{CC} (V) | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Propagation Delay, | $R_L = 1 \text{ M}\Omega$, $C_L = 10 \text{ pF}$ | 0.9 | - | 51.8 | - | - | - | ns |
| | (A or B) to Y (Figures 3 and 4) | | 1.10 to 1.30 | - | 13.8 | 28.6 | - | 30.9 | |
| | , | | 1.40 to 1.60 | - | 7.2 | 12.4 | - | 13.9 | |
| | | | 1.65 to 1.95 | _ | 5.2 | 9.6 | - | 12.1 | |
| | | | 2.3 to 2.7 | - | 3.3 | 7.0 | - | 8.0 | |
| | | | 3.0 to 3.6 | - | 2.7 | 5.7 | - | 6.9 | |
| t _{PLH} , t _{PHL} | | | 0.9 | _ | 52.7 | _ | - | - | ns |
| | (A or B) to Y (Figures 3 and 4) | | 1.10 to 1.30 | - | 14.1 | 29.3 | _ | 33.9 | |
| | , | | 1.40 to 1.60 | - | 7.5 | 13.3 | - | 13.9 | |
| | | | 1.65 to 1.95 | - | 5.4 | 10.3 | _ | 12.1 | |
| | | | 2.3 to 2.7 | - | 3.5 | 7.4 | - | 8.0 | |
| | | | 3.0 to 3.6 | _ | 2.8 | 6.1 | - | 6.9 | |
| t _{PLH} , t _{PHL} | Propagation Delay, | $R_L = 1 \text{ M}\Omega$, $C_L = 30 \text{ pF}$ | 0.9 | - | 55.5 | - | _ | - | ns |
| | (A or B) to Y (Figures 3 and 4) | | 1.10 to 1.30 | _ | 15.2 | 31.4 | - | 43.0 | |
| | | | 1.40 to 1.60 | - | 8.4 | 16.0 | - | 18.0 | |
| | | | 1.65 to 1.95 | - | 6.2 | 12.0 | _ | 14.0 | |
| | | | 2.3 to 2.7 | - | 4.0 | 9.0 | _ | 10.0 | |
| | | | 3.0 to 3.6 | - | 3.3 | 7.0 | _ | 8.9 | |

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Test Condition | Typical (T _A = 25°C) | Unit |
|------------------|--|---|---------------------------------|------|
| C _{IN} | Input Capacitance | V _{CC} = 0 V | 2.0 | pF |
| C _{OUT} | Output Capacitance | V _{CC} = 0 V | 4.0 | pF |
| C _{PD} | Power Dissipation Capacitance (Note 5) | $f = 10 \text{ MHz}, V_{CC} = 0.9 \text{ to } 3.6 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$ | 6.0 | pF |

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption: P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.



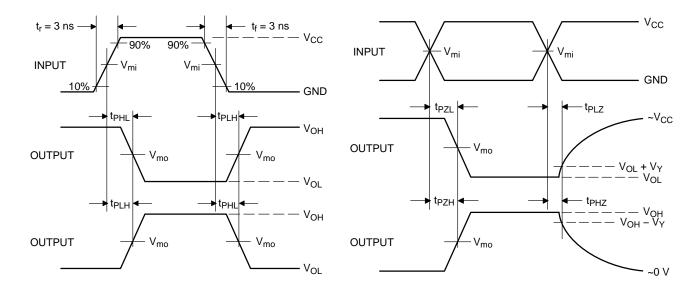
| Test | Switch Position |
|-------------------------------------|---------------------|
| t _{PLH} / t _{PHL} | Open |
| t _{PLZ} / t _{PZL} | 2 x V _{CC} |
| t _{PHZ} / t _{PZH} | GND |

 C_L includes probe and jig capacitance

 R_T is Z_{OUT} of pulse generator (typically 50 Ω)

f = 1 MHz

Figure 3. Test Circuit



| V _{CC} , V | V _{mi} , V | V _{mo} , V | V _Y , V |
|---------------------|---------------------|---------------------|--------------------|
| 0.9 | V _{CC} /2 | V _{CC} /2 | 0.1 |
| 1.1 to 1.3 | V _{CC} /2 | V _{CC} /2 | 0.1 |
| 1.4 to 1.6 | V _{CC} /2 | V _{CC} /2 | 0.1 |
| 1.65 to 1.95 | V _{CC} /2 | V _{CC} /2 | 0.15 |
| 2.3 to 2.7 | V _{CC} /2 | V _{CC} /2 | 0.15 |
| 3.0 to 3.6 | 1.5 | 1.5 | 0.3 |

Figure 4. Switching Waveforms

ORDERING INFORMATION

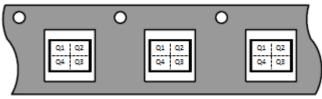
| Device | Package | Marking | Pin 1 Orientation (See below) | Shipping [†] |
|------------|----------|---------|----------------------------------|-----------------------|
| NC7SP32P5X | SC-88A | P32 | Q4 | 3000 / Tape & Reel |
| NC7SP32L6X | MicroPak | K5 | Q4 | 5000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Pin 1 Orientation in Tape and Reel

Direction of Feed

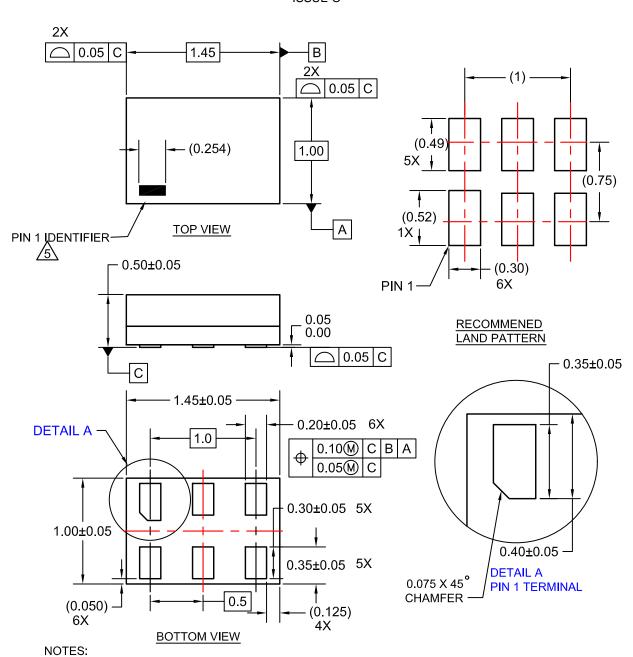




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PACKAGE DIMENSIONS

SIP6 1.45X1.0 CASE 127EB ISSUE O

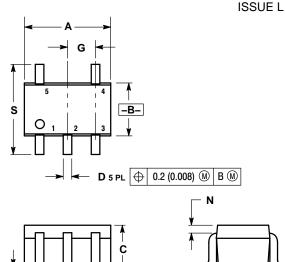


- 1, CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
 4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

OTHER LINE IN THE MARK CODE LAYOUT.

PACKAGE DIMENSIONS

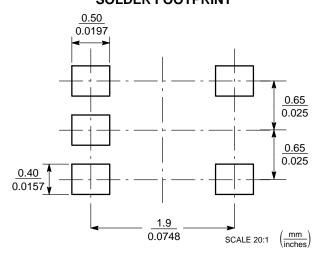
SC-88A (SC-70-5/SOT-353) CASE 419A-02



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
- 419A-01 OBSOLETE. NEW STANDARD 419A-02
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE

| | INCHES | | MILLIN | IETERS |
|-----|-----------|-------|----------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.071 | 0.087 | 1.80 | 2.20 |
| В | 0.045 | 0.053 | 1.15 | 1.35 |
| С | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 | BSC | 0.65 BSC | |
| Н | | 0.004 | | 0.10 |
| J | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 | 0.30 |
| N | 0.008 REF | | 0.20 | REF |
| S | 0.079 | 0.087 | 2.00 | 2.20 |

SOLDER FOOTPRINT



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